

# **Radar Pulsed Power Transistor** 5W, 2.7-3.1 GHz, 100us Pulse, 10% Duty

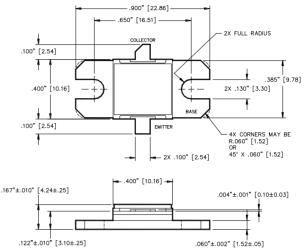
#### Features

- NPN silicon microwave power transistors •
- Common base configuration
- Broadband Class C operation •
- High efficiency inter-digitized geometry •
- Diffused emitter ballasting resistors •
- Gold metallization system •
- Internal input and output impedance matching •

Absolute Maximum Ratings at 25°C

- Hermetic metal/ceramic package •
- **RoHS** compliant •

## **Outline Drawing**



#### .122"±.010" [3.10±.25]

UNLESS OTHERWISE NOTED, TOLERANCES ARE INCHES ±.005" [MILLIMETERS ±0.13MM]

| Parameter                 | Symbol           | Rating      | Units |
|---------------------------|------------------|-------------|-------|
| Collector-Emitter Voltage | V <sub>CES</sub> | 65          | V     |
| Emitter-Base Voltage      | V <sub>EBO</sub> | 3.0         | V     |
| Collector Current (Peak)  | Ι <sub>C</sub>   | 0.7         | А     |
| Power Dissipation @ +25°C | P <sub>TOT</sub> | 50          | W     |
| Storage Temperature       | T <sub>STG</sub> | -65 to +200 | °C    |
| Junction Temperature      | TJ               | 200         | °C    |

# Electrical Specifications: T<sub>c</sub> = 25 ± 5°C (Room Ambient )

| Parameter                           | Test Conditions       | Frequency             | Symbol              | Min | Мах   | Units |
|-------------------------------------|-----------------------|-----------------------|---------------------|-----|-------|-------|
| Collector-Emitter Breakdown Voltage | I <sub>C</sub> = 10mA |                       | $BV_{CES}$          | 65  | -     | V     |
| Collector-Emitter Leakage Current   | V <sub>CE</sub> = 40V |                       | I <sub>CES</sub>    | -   | 1.0   | mA    |
| Thermal Resistance                  | Vcc = 36V, Pin = 1.0W | F = 2.7, 2.9, 3.1 GHz | R <sub>TH(JC)</sub> | -   | 3.5   | °C/W  |
| Output Power                        | Vcc = 36V, Pin = 1.0W | F = 2.7, 2.9, 3.1 GHz | P <sub>OUT</sub>    | 5.0 | -     | W     |
| Power Gain                          | Vcc = 36V, Pin = 1.0W | F = 2.7, 2.9, 3.1 GHz | G <sub>P</sub>      | 7.0 | -     | dB    |
| Collector Efficiency                | Vcc = 36V, Pin = 1.0W | F = 2.7, 2.9, 3.1 GHz | $\eta_c$            | 30  | -     | %     |
| Input Return Loss                   | Vcc = 36V, Pin = 1.0W | F = 2.7, 2.9, 3.1 GHz | RL                  | -   | -6    | dB    |
| Load Mismatch Tolerance             | Vcc = 36V, Pin = 1.0W | F = 2.7, 2.9, 3.1 GHz | VSWR-T              | -   | 3:1   | -     |
| Load Mismatch Stability             | Vcc = 36V, Pin = 1.0W | F = 2.7, 2.9, 3.1 GHz | VSWR-S              | -   | 1.5:1 | -     |

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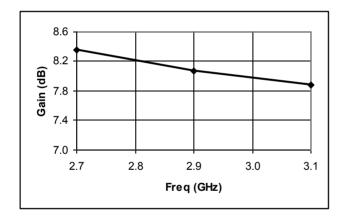


| Radar Pulsed Power Transistor          |  |  |  |  |  |
|--|--|--|--|--|--|
| 5W, 2.7-3.1 GHz, 100µs Pulse, 10% Duty |  |  |  |  |  |

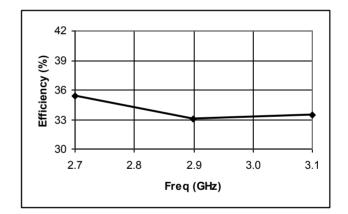
### **Typical RF Performance**

| Freq.<br>(GHz) | Pin<br>(W) | Pout<br>(W) | Gain<br>(dB) | lc<br>(A) | Eff<br>(%) | RL<br>(dB) | VSWR-S<br>(1.5:1) | VSWR-T<br>(3:1) |
|----------------|------------|-------------|--------------|-----------|------------|------------|-------------------|-----------------|
| 2.7            | 1.0        | 5.6         | 7.47         | 0.48      | 32.6       | -12.8      | S                 | Р               |
| 2.9            | 1.0        | 6.1         | 7.83         | 0.50      | 33.5       | -16.7      | S                 | Р               |
| 3.1            | 1.0        | 6.2         | 7.89         | 0.51      | 33.8       | -20.5      | S                 | Р               |

Gain vs. Frequency

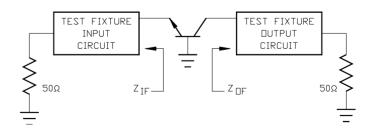


## **Collector Efficiency vs. Frequency**



#### **RF Test Fixture Impedance**

| F (GHz) | Z <sub>IF</sub> (Ω) | Z <sub>OF</sub> (Ω) |
|---------|---------------------|---------------------|
| 2.7     | 40 - j12            | 25 + j3.5           |
| 2.9     | 35 - j16            | 16 + j2.4           |
| 3.1     | 30 - j18            | 12 + j4.0           |



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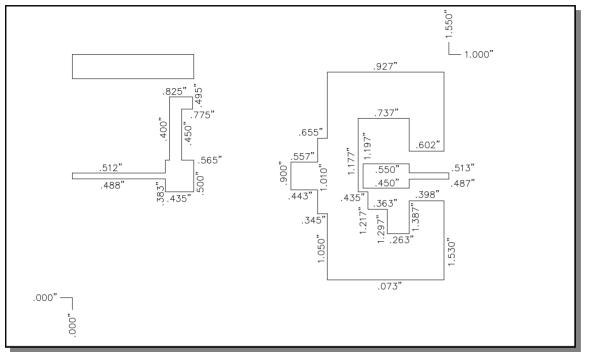
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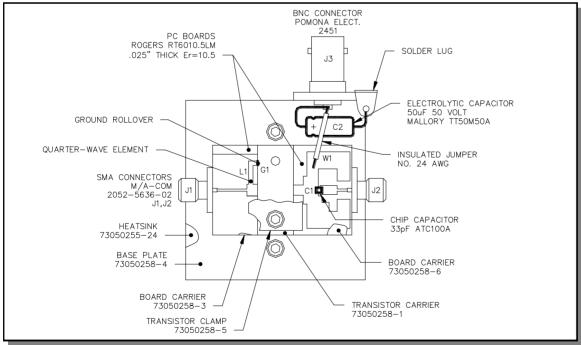


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### **Test Fixture Circuit Dimensions**



#### **Test Fixture Assembly**



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